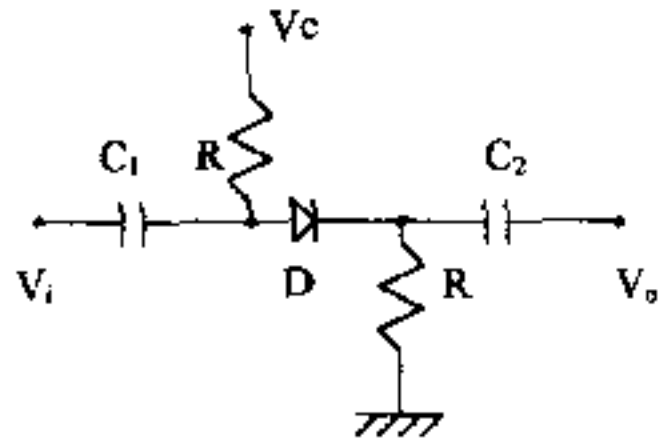


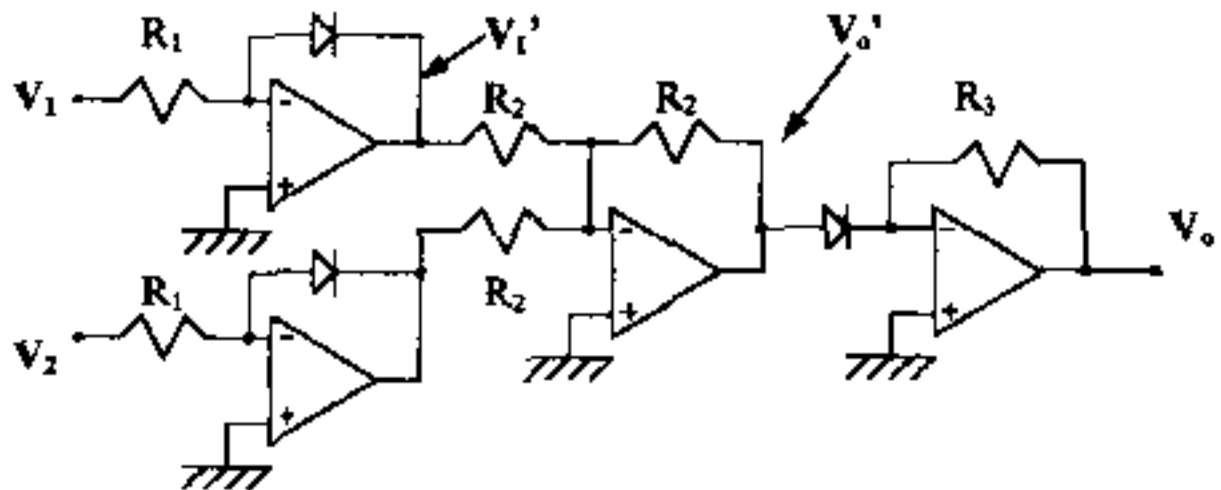
1. In the circuit, the capacitors are $C_1=C_2=\infty$. The diode has a cut-in voltage V_D and I-V characteristics of $I_D=I_s \exp(V_D/V_T)$. The input V_i is a small ac signal. The control voltage V_c is a variable dc voltage.

- (a) Sketch the small-signal equivalent circuit.
 (b) Find the output voltage V_o as function of V_c .
 (8%)



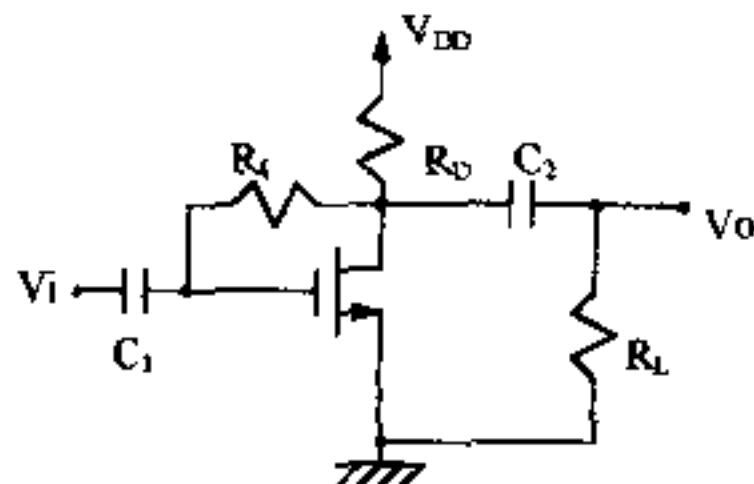
2. In the circuit, the op-amps are ideal and the diodes are characterized by $I_D=I_s \exp(V_D/V_T)$. The voltages V_1 and V_2 are positive. Find the voltages V_1' , V_o' and V_o .

(12%)

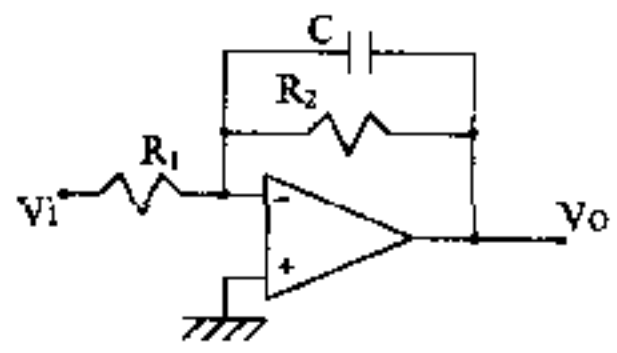


3. In the circuit, the capacitors are assumed $C_1=C_2=\infty$. The MOSFET has given k and V_t values.

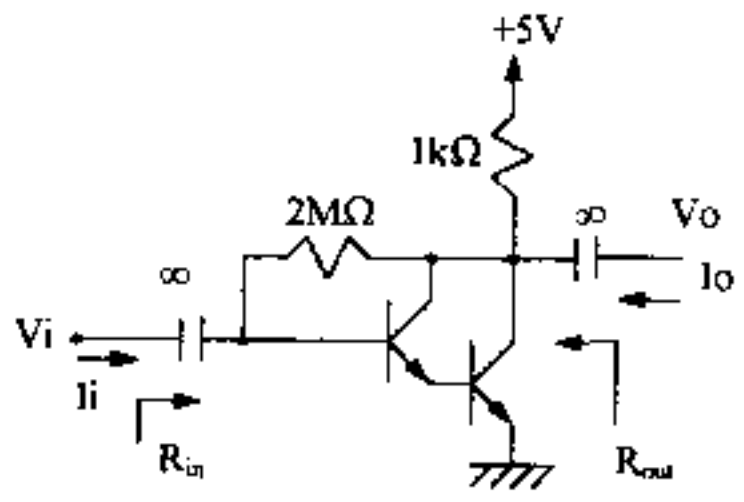
- (a) Find R_D such that $V_{DS}=V_{DD}/2$.
 (b) Sketch the small signal equivalent circuit and find the voltage gain V_o/V_i .
 (12%)



4. For the circuit shown, the op-amp is ideal.
- (a) Find the dc gain and the 3-dB frequency.
 - (b) Design the values of resistors and capacitor so as to obtain an input resistance of 2 k Ω , a dc gain of 40 dB, and a 3-dB frequency of 4 kHz. What is the unity-gain bandwidth f_T ?
- (10%)



5. For the circuit shown,
- (a) perform its DC analysis,
 - (b) sketch its small-signal equivalent circuit,
 - (c) calculate the open-circuit voltage gain, the short-circuit current gain, the input resistance, and the output resistance. Note that the β of the transistors is equal to 100.
- (23%)



八十七學年度 電機工程 系(版) 乙 組碩士班研究生入學考試

科目 電子學 科號 3002 共 三頁第 三頁 請在試卷【答案卷】內作答

6. For the function of $Y = \overline{AB} + \overline{CD}$ with inputs $A, \bar{A}, B, \bar{B}, C, \bar{C}, D,$ and \bar{D} available. You can take the TTL circuits or ECL circuits as 2-input logic gates.
- Draw the gate-level scheme of open-collector TTL circuit to implement Y . You have to show the output connections and pull-up device.
 - Draw the transistor-level scheme of a CMOS gate to implement Y .
 - Draw the gate-level scheme of ECL wired-function to implement Y . (12%)
7. For the second-order band pass transfer function,
- Write down the equation $T(S)=?$
 - Use R, L, C only (one of each) to implement the band pass function. (Draw the circuit)
 - Find the center-frequency gain in terms of $R, L,$ and C .
 - Find the sensitivity $S_C^{W_0}$, where W_0 means center-frequency.
 - Draw the circuit that replaces the R in (b) with the switched-capacitor realization. (15%)
8. Using three resistors with values $R_1, R_2, R_3,$ a capacitor with value C and an ideal op amp with saturation voltage L (max.) and $-L$ (Min) to **build** an astable multivibrator that can produce square wave. Also **calculate** the period in terms of $R_1, R_2, R_3, C,$ and L . (8%)